M agnetic eld e ects on low dim ensional electron system s: Luttinger liquid behaviour in a Quantum W ire

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W e discuss the e ects of a strong magnetic eld in Q uantum W ires. W e show how the presence of a magnetic eld modi es the role played by electron electron interaction producing a strong reduction of the backward scattering corresponding to the C oulom b repulsion. W e discuss the consequences of this and other e ects of magnetic eld on the Tom onaga-Luttinger liquids and especially on their power-law behaviour in all correlation functions.

The focal point is the rescaling of all the repulsive terms of the interaction between electrons with opposite momenta, due to the edge localization of the electrons and to the reduction of the length scale. Because of the same two reasons there are some interesting elects of the magnetic eld concerning the backward scattering due to the presence of one in purity and the corresponding conductance. As an elect of the magnetic eld we indicate a spin polarization induced by a combination of electrostatic forces and the Pauliprinciple, quite similar to the one observed in large Q untum D ots.

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I. IN TRODUCTION

In the last 20 years progresses in sem iconductor device fabrication and carbon technology allowed the construction of several new devices at the nanom etric scale and m any novel transport phenom ena have been revealed in m esoscopic low-dim ensional structures.

M olecular beam epitaxy allows one to construct interesting two-dimensional devices in heterostructures between dimensional devices in heterostructures betric eld creates a two dimensional electron gas (2D EG) at the interface) while other techniques (such as the electron beam lithography) for the deposition of metallic gates allow us to con ne electrons in small devices with controllable size and contact transparency¹.

Sem iconductor Q uantum W ires (QW s) are quasionedim ensional(1D) devices where the electron waves are in som e ways analogous to electrom agnetic waves in waveguides. They are made from a 2DEG at the interface of a GaAs : A IG aAs heterojunction where a quasi one dim ensional electron gas can be form ed by etching the heterojunction into a wire of width, say, $1000A^{1}$.

The transport in QW s is connected to three different regimes, the two ones at very low temperatures correspond to the typical single electron tunnelling (C oulom b blockade) and to B allistic Transport (where the Landauer-Buttiker form alism applies)^{2,3,4} while when the correlation is strong the Tom onaga-Luttinger^{5,6,7,8} liquid regime dom inates.

Experiments with short one-dimensional (1D) conductors (QWs, narrow ballistic channels, quantum point contacts in a 2DEG and Carbon Nanotubes) have demonstrated^{9,10} that their conductance is quantized in integer multiples of $2e^2$ =h. How ever, this simple step-like form for the conductance as a function of the Fermien-

ergy, occurs when the transition between the wide leads and the narrow channel is adiabatic 11 .

The ballistic transport characterizes the motion of electrons in nanom etric regions in sem iconductor structures at very high electric eld when velocities are much higher than their equilibrium therm alvelocity. We suppose that ballistic electrons are not subjected to scattering with others electrons. A general model for near-equilibrium ballistic transport is due to the Landauer³ and Buttiker⁴ contributions that are condensed in the so called Landauer form ula. This form ula expresses the conductance of a system at very low tem peratures and very sm allbias voltages in terms of the quantum mechanical transm ission coe cients. The conductance is calculated directly from the energy spectrum by relating it to the number of forw ard propagating electron modes at a given Ferm i energy.

Electron transport in QW s attracts considerable interest also because of the fundam ental importance of the electron-electron (e-e) interaction in 1D system s: the e-e interaction in a 1D system is expected to lead to the form ation of a Tom onaga-Luttinger (TL) liquid with properties very di erent from those of the non-interacting Ferm igas^{8,12,13}.

In the TL m odel two types of ferm ions right m overs and left m overs are coupled by an interaction of strength g. The interaction between electrons in one-dimensional m etals gives several singular properties not present in conventional (Ferm i liquid) m etals: (i) a continuous m om entum distribution function n (k), varying with k as $k_{\rm F}$ j w ith an interaction-dependent exponent , consequence of the lack of ferm ionic quasi-particles; (ii) a sim ilar power-law behaviour in all correlation functions; (iii) charge-spin separation: the elem entary excitations of a TL liquid are not quasi-particles, with charge e and spin 1=2 but collective charge and spin density uctuations with bosonic character, i.e. so-called spinons and holons. These spin and charge excitations propagate with di erent velocities which lead to the separation of spin and charge.

The interest in TL liquids increased in recent years because of several new physical realizations, including quantum H alledge system $s^{5,14,15}$, carbon nanotubes 16,17 , and sem iconductor QW $s^{18,19}$ in particular. M ost of these experiments concentrated on the power-law behavior of the electron tunneling.

The low-energy behavior of Luttinger liquids is dramatically a ected by impurities and Carbon nanotubes enable experimentalists now adays to analyze systems with a single impurity in an otherwise perfectly pure onedimensionalmetal.

Because of the electron-electron interaction the backscattering amplitude generated by the impurity grows at low energy scales, so that the impurity acts as an increasingly high barrier²⁰. A power-law singularity of the $2k_F$ density response function in a Luttinger liquid can con rm this behavior. As a consequence, universal scaling behavior is expected in the low energy limit, with exponents depending only on bulk parameters of the system, rather than on the impurity strength.

A Luttinger liquid in strong magnetic eld can be dramatically modied by spin e ects. The presence of a strong magnetic eld acting on a many electron system can induce a spin polarization. In sem iconducting devices this polarization is not an e ect of Zeem an coupling but it could be a result of the Coulom b exchange or a consequence of a transverse electric eld always present at the interface (Rashba e ect) 21,22,23 . In fact the Spin Orbit (SO) coupling due to the electric eld in the z direction is stronger than the Zeem an term of interaction connected to a magnetic eld acting on the system because of the strong reduction of the e ective electron mass (m = $0.068m_0$). The Zeeman spin splitting term is $g_{B}B$ where g_{B} is the elective magnetic factor for electrons in this geometry (very low in GaAs) and is the Bohr m agneton with the bare m ass. So the m ass renorm alization reduces by a factor 10 the SO coupling and by a factor 100 the Zeem an spin splitting.

The spin behavior of an electron liquid under the effect of a strong magnetic eld was accurately studied in a di erent nanom etric sem iconducting device, the Q uantum D ots (QDs), which are small structures (typically less than 1 m in diam eter) containing from one to a few thousand electrons. In QDs the electronic spins align when a strong magnetic eld is present and it is known that magnetism occurs not because of direct magnetic forces (Zeem an coupling or SO coupling), but rather because of a combination of electrostatic forces and the Pauliprinciple as was proven in the last decade in several experiments²⁵.

In this paper we present a study of the magnetic eld dependence of Luttinger liquids in QW s. In section Π we introduce the model for a QW under the action of a magnetic eld. In section III we discuss the e ect of the magnetic eld on the kinetic and interaction coe cients as well as on the derived param eters. In particular we analyze the e ects of the magnetic eld on the critical coe cient which characterizes the transport of the W ire because it determ ines the power law behaviour of the Density of the States. In section III we also discuss the e ects of one impurity by analyzing the e ects of magnetic eld on the conductance. In section IV we analyze how a spin polarization could be observed in QW s in analogy with what happens in large Q D s; we also discuss the e ects on Luttinger liquid behaviour due to the spin polarization which implies the transition from a spinful Luttinger liquid to a spinless one.

II. HAM ILTON IAN AND M ICROSCOPIC APPROACH

A QW is usually de ned by a parabolic con ning potential along one of the directions in the plane^{22,23,26}: V (x) = $\frac{m_{\odot}}{2}!_{d}^{2}x^{2}$. We also consider a uniform magnetic eld B along the \hat{z} direction which allows a free choice in the gauge determination. We choose the gauge so that the system has a symmetry along the \hat{y} direction, A = (0; B x; 0), so that the single particle H am iltonian is

$$H = m_{e} \frac{v^{2}}{2} + \frac{m_{e}!_{d}^{2}}{2}x^{2}$$
(1)

where $m_e v_y = p_y$ eB x=($m_e c$) and $m_e v_x = p_x$.

In order to solve the H am iltonian for QW s we introduce the cyclotron frequency $!_{\rm c} = \frac{eB}{m\,c}$ and the total frequency $!_{\rm T} = \frac{p}{!_{\rm d}^2 + !_{\rm c}^2}$ and point out that $p_y = v_y + eB \, x = (m\,_{\rm e}\,c)$ commutes with the H am iltonian

$$H = \frac{!_{d}^{2}}{!_{T}^{2}} \frac{p_{y}^{2}}{2m_{e}} + \frac{p_{x}^{2}}{2m_{e}} + \frac{m !_{T}^{2}}{2} (x - x_{0})^{2}; \qquad (2)$$

where $x_0 = \frac{!_{c}p_y}{!_T^2 m_e}$. The classicalH am ilton equations give us the orbitalm otion in the special case of vanishing $\underline{x}(0)$

where the drift velocity is $v_d = \frac{!\frac{2}{d}p_y}{!\frac{2}{T}m_e}$. We obtain $p_y = m_e(\underline{y}_{(0)} + !_c x(0)), y(0) = 0$ and R = x(0) x_0 from the boundary conditions. The two di erent motions along the W ire are localized on the two di erent edges, as we can argue from the introduction of p_y ! v_d . These are also known in quantum mechanics as edge states²⁶.

The quantum mechanics approach to the single particle H am iltonian in eq.(2) gives two term : a quantized harm onic oscillator and a quadratic free particle-like dispersion. This kind of factorization does not re ect itself in the separation of the motion along each axis because the shift in the center of oscillations along x depends on the momentum k_y . Therefore each electron in the system has a de nite single particle wave function

$$'_{n;k_y}(x;y) = u_n(x - x_0(k_y)) \frac{e^{ik_y y}}{2L_y};$$

$$u_n (x ! k) = \frac{1}{p} = e^{\frac{(x ! k)^2}{2 !}} h_n (x ! k):$$

Here $h_n (x = x_0 (k_y))$ is the n Herm ite polynom ial shifted by $x_0 (k_y) = \frac{1}{2} k_y$ where $\frac{1}{2} = \frac{\frac{1}{2} \frac{h}{m_e!_\pi}}{\frac{h}{m_e!_\pi}}$ and $\frac{1}{2} = \frac{\frac{h}{m_e!_\pi}}{\frac{h}{m_e!_\pi}}$. In what follows we assume $0 = \frac{1}{\frac{m_e!_\pi}{m_e!_\pi}}$ (corresponding to zero magnetic eld) as the characteristic length of the system when the magnetic eld vanishes.

Now we are ready to give a simple expression of the free electron energy depending on both the y m om entum k and the chosen subband n:

$$"_{n,k} = \frac{!_{d}^{2}}{2m_{e}!_{T}^{2}}h^{2}k^{2} + h!_{T}^{2}(n + \frac{1}{2})$$

Below we limit ourselves to electrons in a single channel (n = 0), where N electrons occupy the lowest energy levels. We obtain the value of the Ferm i wavevector as $k_{\rm F}=\frac{N}{4}~k$ where $~k=\frac{2}{T_{\rm e}}$.

The typicalLuttingerm odel starts from the hypothesis that the Ferm i surface consists of two Ferm i points, in the neighborhood of which the dispersion curve can be approxim ated by straight lines with equations

In our case we obtain a eld-dependent free Ferm ivelocity

$$v_{\rm F} = \frac{!_{\rm d}^2}{m_{\rm e}!_{\rm T}^2} h k_{\rm F} - \frac{!_{\rm d}^2}{m_{\rm e}!_{\rm c}^2} h k_{\rm F}; \qquad (5)$$

where the approximation is valid for very strong elds.

W e introduce di erent operators for the electrons belonging to each branch: right going operators $c_{R,\overline{k},s}^{y}$ and left going ones $c_{L,\overline{k},s}^{y}$ for electrons with $\overline{k} > 0$ ($\overline{k} < 0$). In term s of these operators the free and interaction H am iltonians can be written as

$$H_{0} = v_{F} \frac{X}{\bar{k}c_{R}^{y};\bar{k};s}c_{R};\bar{k};s} + v_{F} \frac{X}{\bar{k}c_{L}^{y};\bar{k};s}c_{L};\bar{k};s}$$
(6)

$$H_{int} = \frac{1}{L} \sum_{k;k^{0};q;s;s^{0}}^{X} V_{k;p}^{s;s^{0}}(q) C_{k+q;s}^{y} C_{p-q;s^{0}}^{y} C_{p;s^{0}}^{s} C_{k;s}$$
(7)

Here $q_k \quad q_{;k}$ if k > 0 and $q_k \quad q_{;k}$ if k < 0, while $V_{k;p}^{s;s^0}(q)$ is the Fourier transform of the electron electron interaction.

The scattering processes are usually classi ed according to the di erent electrons involved and the coupling strengths labelled with g are often taken as constants. In fact, as discussed in detail by Solyom¹³, we can substitute $V_{k,p}^{s;s^0}$ (q) with 8 constants. In general we should take into account the dependence on k;p and q, however in a model with a bandwidth cut-o , where all momenta are restricted to a small region near the Ferm i points, the momentum dependence of the coupling is usually neglected.

We can write $g_4^{\text{s};\text{s}^0}$ for k and p in the same branch and small q (transferred m om entum): $g_4^{\text{s};\text{s}^0}$ corresponds to the Forward Scattering in the same branch. We use $g_2^{\text{s};\text{s}^0}$ for the Forward Scattering involving two branches where k and p are opposite and q is small. The Backward Scattering $(g_1^{\text{s};\text{s}^0})$ involves electrons in opposite branches with large transferred m om entum (of order $2k_F$). We do not take into account the e ects of Um klapp scattering $(g_3^{\text{s};\text{s}^0})$.

The model described above, with linear branches and constant interaction in momentum space is known as TL model and corresponds to a very short range interaction (D irac delta). The presence of a long range interaction in a 1D electron system introduces in the model an infrared divergence and is quite di cult to solve. We reported the solutions for the case of C arbon N anotubes obtained with a R enormalization G roup approach and a D in ensional C rossover in some recent papers²⁷, and in the future we will apply that formalism to the case of a QW in the presence of magnetic eld.

Below we limit ourselves to the TL model and our main results refer to the short range interaction, with the aim of giving a qualitative explanation of the e ects of a strong transverse magnetic eld.

III. LUTTINGER LIQUID PARAMETERS

A. E ective param eters

All properties of a TL liquid can be described in terms of only two e ective parameters per degree of freedom which take over in 1D the role of the Landau parameters fam iliar from Ferm i liquid theory.

In particular the low-energy properties of a hom ogeneous 1D electron system could be completely specied by the TL coe cients corresponding to the interaction $(g_i^{s_i})$ and the kinetic energy (v_F) in the limit of ideal TL liquid.

Four TL parameters, depending on g and v_F , characterize the low energy properties of interacting spinful electronsm oving in one channel: the parameter K xes the exponents form ost of the power laws and v is the

velocity of the long wavelength excitations: = for the charge and = for the spin. The parameters²⁴ K and v₌ are easily obtained as functions of $g_i^{s_i}$ and v_F by various techniques found in textbooks¹³.

$$K = \frac{v_{\rm F} + g_4 - g_2}{v_{\rm F} + g_4 + g_2}$$
(8)

$$v = v_F + \frac{q_4}{2} + \frac{q_2}{2} + \frac{q_2}{2}$$
 (9)

$$= \frac{1}{2} (v_F + \frac{g_4}{v}) \frac{1}{v} + (v_F + \frac{g_4}{v}) \frac{1}{v} - 2$$
 (10)

where $g_i=\frac{1}{2}\left(g_i^k \quad q^2\right)$ and $g_i=\frac{1}{2}\left(g_i^k+g_i^2\right)$. Here denotes the critical exponent which characterizes many properties of the transport behaviour of a 1D device (e.g. the zero bias conductance as a function of T, which is well described by a power law behavior G = T). In this paper we discuss m icroscopic estimates of the values of these quantities in sem iconductor QW s when a strong transverse magnetic eld is present.

B. Coupling Constants

At the end of the previous section we discussed how the electron electron repulsion has a very simple and detailed representation in the TL model¹³ where the g_i^{s,s^0} coe cients contain all the information about the interaction. In this subsection we want evaluate the g coe cients which characterize the Ham iltonian eq.(7). In order to do that, we have to calculate the "Fourier transform " V_{k,k^0}^{n,n^0} (g;!c) of the elective interaction starting from some models. This is our crucial problem and gives us the g coe cients. In this article we lim it ourselves to the one channel model (n = n⁰ = 0) and we introduce the magnetic eld dependent elective potentials

$$U_{k;p;q}^{s;s} (y \quad y_{j}^{0}; !_{c}) = dx dx^{0} U (jc \quad r^{0})$$

$$u_{0} (x \quad ! k) u_{0} (x \quad ! p)$$

$$u_{0} (x^{0} \quad ! (k+q)) u_{0} (x^{0} \quad ! (p \quad q)) :$$

These potentials only depend on $y = y^0$ and on the 1D ferm ion quantum numbers.

Now we are ready to calculate the "Fourier transform " in order to obtain V (q). A central question regards the spin e ects on the coupling strength. In the Hartree-Fock approximation the so called direct term corresponds to q = 0 (V (0)) while the exchange one corresponds to $q = p \quad k (V (q))$. Is evident that the electron electron repulsion is less for electrons with the same spin ($V_q^{""} =$ V (0) V (q))than for electrons with opposite spins ($V_q^{""} =$ V (0)).

In order to analyze the e ects of the range of the interaction we introduce a function for the electron electron potential depending on a param eter r. This general interaction m odel, ranges from the very short range one to the in nity long range one and elim inates the divergence of the C oulom b repulsion

$$U(x \quad x^{\rho} ; y \quad y^{\rho}) = \frac{g_{0} \quad {}_{0}^{2} = + g_{1} \; r^{2}}{r^{2}}$$
$$exp \quad \frac{(x \quad x^{\rho})^{2} + (y \quad y^{\rho})^{2}}{r^{2}} ; (11)$$

where g_0 and g_1 are the copuling constant corresponding to the two di erent limits of r (r ! 0 delta function $U = g_0 {}^2_0$ (jx x) and constant interaction r ! 1 $U = g_1$).

So we can calculate $V_{k,p}$ (q; ! c) by a simple integral

$$V_{k,p}(q; !_{c}) = \frac{q_{0} \ _{0}^{2} = + q_{1} \ r^{2} \ _{p}^{P} - \frac{1}{L_{y}} \frac{p \ _{r}^{2} + 2 \ _{1}^{2}}{L_{y} \ _{r}^{2} + 2 \ _{1}^{2}}$$

$$exp \ \frac{q^{2} \ r^{2}}{4} \ _{1}^{2} \ \frac{q^{2}}{2 \ _{1}^{2}} + \frac{(k \ p + q)^{2}}{r^{2} + 2 \ _{1}^{2}} \qquad :(12)$$

Thusweput

$$g(\mathbf{r}; !) = \frac{g_0 \ _0^2 = + g_1 \ \mathbf{r}^2 \ ^p -}{L_y \ ^p \ \mathbf{r}^2 + 2 \ _1^2}:$$

Som e details about the com parison between C oulom b interaction and the model of electron electron interaction in eq.(11) are given in appendix.

Now we are ready to calculate the coe cients in eq.(7).

(a) The so called forward scattering in the same branch (g₄) involves electrons with p k, i.e. $k = \frac{1}{p} + \frac{1}{k}$: for parallel spins we have $g_4^k = V_k(0) = V_k(k)$ while for orthogonal spins we just have V (0)

$$V_{k}(0) = g(r;!) \exp \left(\frac{2}{!} \frac{k^{2}}{r^{2} + 2\frac{2}{!}}\right) g(r;!):$$

So we can assume $g_4^k = 0$ and $g_4^2 = g(r;!)$.

(b) The forward scattering between opposite branches, which is usually called g_2 and corresponds to p k_F ; k k_F ! k $2k_F$, where a small momentum

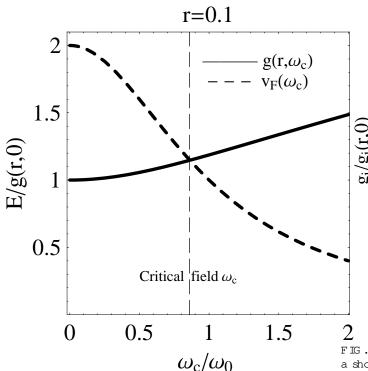
is transferred q 0, gives as a rst approximation

$$g_2^k = g_2^?$$
 V_{2k_F} (0) = g(r;!) exp $\frac{2}{!} \frac{4k_F^2}{r^2 + 2\frac{2}{!}}$:

(c) For the backward scattering g_1 , p k_i ; k k_F ! k $2k_F$ with a large momentum transferred q $2k_F$, we have

$$V_{k}(0) = g(r; !) \exp 4k_{F}^{2} - \frac{r^{2}}{4} + \frac{2}{2 \cdot \frac{2}{2}} + \frac{4 \cdot \frac{2}{2}}{r^{2} + 2 \cdot \frac{2}{2}}$$
:

Now we can discuss the e ects of a magnetic eld on the interaction terms and the kinetic coe cient.



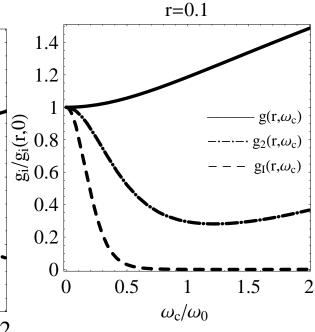


FIG.2: Scaling of the interaction with the magnetic eld for a short range of interaction r = 0:1. Each value of g(!) is renormalized with respect to the value at zero magnetic eld $(!_{c} = 0)$.

FIG. 1: Graphic calculation of the critical eld: the spin transition is due to the simultaneous reduction of the Ferm i velocity and increasing of the electron electron repulsion. In the y-axis we report the energy E in units of g(r;0), for a starting value $v_{\rm F}$ = 2g(r;0).

I)A strong reduction of the Ferm i velocity when the magnetic eld increases is very clear, as displayed in Fig.(1) where $v_{\rm F}$ (!_c) is reported.

II)The forward scattering between electrons in the same branch increases with the magnetic eld as shown in Fig.(2) $(g_4 / g(r;!_c))$. We can also observe that the long range component of this interaction is less a ected by the growing eld Fig.(3).

III) The backscattering (g_1) is strongly reduced by the magnetic eld and it gives a smaller contribution to the physics of the system when the magnetic eld increases. A lso in this case the e ect is smoothed if the interaction has long range but is how ever strong.

IV) The forward scattering (g_2) between opposite branches has a strong reduction if we consider the short range component while the e ect is not so clear if we take into account long range interactions.

The dependence of the coupling constants g_i on the magnetic eld shows a competitive e ect of the current localization against the reduction of the characteristic length $\, : \, .$

The localization of the electrons on the opposite edges of the wire is responsible for the strong reduction of the two constant g_2 and g_1 , especially when we consider a short range interaction. The localization is clearly seen in eq.(2), where we introduced x_0 as a function of the

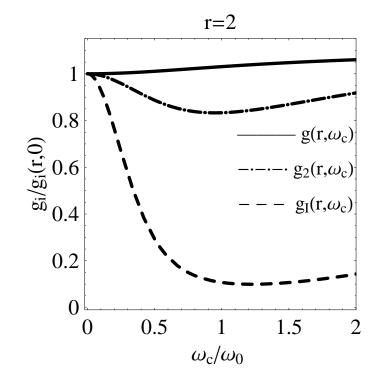


FIG. 3: Scaling of the interaction with the magnetic eld for a long range of interaction r = 2. Each value of g(!) is renorm alized with respect to the value at zero magnetic eld $(!_{\circ} = 0)$.

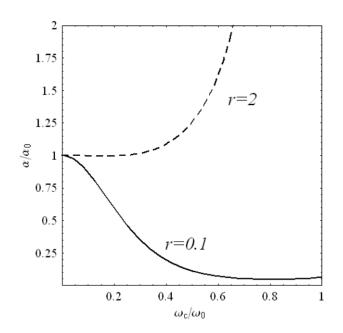


FIG. 4: The critical exponent calculated following textbooks in the lim it of exactly solvable model: the range of interaction determines either a vanishing or a divergent $\$.

m om entum, i.e. of the drift velocity. So we can conclude that electrons with opposite drift velocities are localized in the opposite edges and a reduction in the interaction has to be observed, due to the distance between the opposite currents. O by buy this discussion is not valid if the range of the interaction is not nite.

The e ects of the localization on the coupling constants are partially mitigated by the reduction of the length scale $\frac{1}{2}$ due to the growth of the magnetic eld. The typical length of the system reduces with the magnetic eld and increases the e ective charge density of the electron liquid. As we know, all coupling constants depend on g(r;!_c) and follow its behavior when the magnetic eld increases. However, just the interaction between electrons in the same branch is really enhanced by the magnetic eld if we take in account the localization.

Because of the discussed failure of the TL m odel for a long range interaction, in order to obtain the following results we lim it ourselves to the small range (r) case.

C. The critical exponent

B ecause of our know ledge of the coupling constants we are ready to approach the problem of calculating the critical exponent which characterizes the transport properties of the 1D electron systems. In fact, from the transport m easurem ents it is possible to evaluate the Tunnel D ensity of States with its typical power law dependence. U sually the backscattering e ect is not included in the m odels²⁷ or is taken in to account as a perturbation⁸,

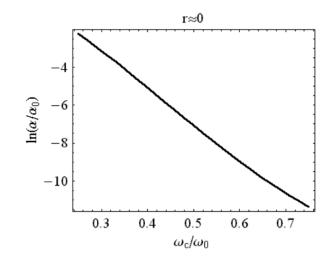


FIG. 5: The critical exponent calculated the intermediate regime, where $1=4 < !_c=!_d < 3=4$, the log-log plot shows the agreement with the exponential behaviour $_0e^{\frac{!c}{!_d}}$

so that here we do not consider g_1 m ore. The role of g_2 is very crucial in order to determ ine the critical exponent 12 which characterizes the linear temperature dependence of the resistance above a crossover temperature T_c in a TL liquid. W hen g_2 vanishes the so called chiral Luttinger liquid with also null appears (in that case the spin-charge separation of excitation is present but no correlation characterizes the G round State).

The dependence of on the magnetic eld is our main prediction and strongly depends on the eld-dependent coe cients in eq.(10)¹³. In Fig.(4) we show the strong suppression of when the magnetic eld increases for a small range potential. Results were obtained for values of the magnetic eld !_c < !_d because as we show in the next section the behaviour of the TL liquid is strongly modiled in the high magnetic eld regime. So we can discuss the behaviour of the critical exponent just in the weak magnetic eld limit and in an intermediate one for a very short range interaction. For a very low magnetic eld we can calculate

where A = $\frac{gG_0}{L_y}$ and $v_F^0 = \frac{hk_F}{m_e}$. In the interm ediate regime, where 1=4 < $!_c=!_d < 3=4$, the critical exponent reduces as follows

0e !a

where the constant is a quite complicated function depending on A , v_F^0 and k_F . This behaviour is clearly seen in Fig.(5). Now we can answer the question, how the magnetic eld alters the D ensity of States exponents in the limit of short range interaction: the attenuation

of the forward scattering between opposite branches due to the localization of the edge states is responsible for the reduction of the critical exponent. This e ect dom - inates and characterizes the TL liquid below a value of the magnetic eld where the spin polarization crossover takes place. At higher elds, as we discuss in the next section, the spin polarization causes a further reduction of .

In Fig.(4) we also show the critical exponent calculated for a long range interaction by using the TL m odel. As we discussed at the end of sec. II, the TL m odel fails when it is applied to the long range interaction because it intrinsically refers to a short range interaction. The divergent behaviour of the exponent when the m agnetic

eld increases con rm s the failure of the m odel in treating the long range interaction.

D. Impurity and Backward scattering

Now we want to shortly discuss how the magnetic eld acts on the TL liquid when also an impurity is present in the wire. We do not give details about calculations discussed in refs.(15,20,28) where the problem is mapped onto an elective eld theory using bosonization and then approached by using a Renormalization G roup analysis. The usual calculations start from a TL model with a scattering potential at the middle point of the wire (x = 0 and y = 0) in which only forward scattering is included as electron electron interaction. Two opposite lim its are usually considered: the weak potential lim it and the strong potential or weak tunneling lim it. The calculation usually starts from the transmission probability obtained for non-interacting electrons with a D irac delta model for the impurity (V (y) = V₀ (y)) with

$$\frac{1}{1 + (\frac{V_0}{hv_F})^2}:$$

As discussed by K ane and F isher²⁰ the Born approximation can be used in the small barrier limit for noninteracting electrons. This hypothesis allows us an easy calculation of the term which plays a central role in the scattering: V ($2k_F$) i.e. the Fourier transform of the potential at $2k_F$. In fact²⁹ the terms which represent scattering with momentum transfer q $2k_F$ do not affect the conductance in any noticeable way, because they do not transfer particles between k_F and k_F . On the other hand, the terms which represent scattering with jrj' $2k_F$ are expected to a ect the conductance, because they change the direction of propagation of the particles. So we introduce a potential in order to describe the im – purity localized at the center of the wire

$$V(x;y) = U_0 \frac{0}{R_0} e^{\frac{x^2 + y^2}{R_0^2}}$$

where R_0 and U_0 represent, respectively, the range and the strength of the in purity potential.

$$V (2k_F) = \frac{p \overline{2} V_0 R_0 e^{k_F^2} 2R_0^2 + \frac{1^2}{12}}{q \overline{\frac{1}{2R_0^2} + \frac{1}{2}} !^2}$$

The strong reduction of the electron backward scattering due to the inpurity depends on the magnetic eld and is clearly due to the discussed localization of the edge states. This allows us to consider the weak potential lim it, in order to proceed to the Renorm alization G roup analysis. The RG equation for $V = V (2k_F)$ can be found as follows:

$$\frac{dV}{d'} = 1 \frac{1}{2}(K + K) V = (1 - g_k)V$$

where $E = E_0 e^{\cdot}$ is the renormalized cut-o and E_0 is the original one. In absence of magnetic eld we can conclude that in our case, where $g_K < 1$ corresponding to repulsive electron electron interaction, V (') scales to in nity. Thus at very low temperature (T = 0) we have a perfect re ection. However we can write a formula for the weak potential limit which gives the conductance as a function of V_0 , g_K and the temperature T if the temperature is T = 0

$$G_{WL} = \frac{e^2}{h} \ 1 \ gV_0^2 T^{2g_K} \ 2 + ...$$
 (13)

where ::: represent higher orders in V and T as in ref.¹⁵. As we know from the previous discussion the magnetic eld acts on eq.(13) by modifying both g_k and V_0 . The form ula eq.(13) rescales the conductance to 0 (total reection) for $g_K < 1$ and tem perature below a threshold tem perature. In the lim it of validity of the eq.(13) we dene the threshold tem perature as the one for which the conductance vanishes

$$T_{s}$$
 (GV₀²) $\frac{1}{2g_{K}^{2}}$:

As we show in Fig.(6) we obtain a strong reduction of the value of T_s , due to the reduction of the single particle backscattering and to the rescaling of g_K which approaches the value 1 corresponding to the marginal case of free electrons.

IV. MAGNETIC INDUCED PHASE TRANSITION: THE SPIN POLARIZATION

In this section we want to discuss what happens at very strong magnetic eld when a spin transition takes place in a low dimensional electron liquid.

The spin behaviour of an electron liquid in the presence of a growing transverse magnetic eld was studied with som e details in QDs. In 1996 K lein et al.^{30,31,32} m easured the position of the conductance peaks as a function of the magnetic eld in a large QD in the Coulomb B lockade

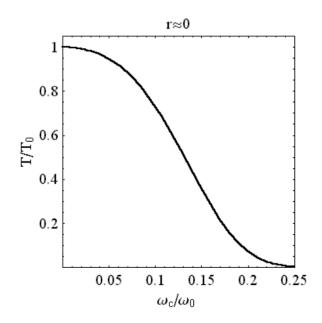


FIG. 6: The strong reduction in the value of the threshold temperature T, due to the reduction of the single particle backscattering and to the rescaling of g_{K} . The values are related to the value T_{0} , corresponding to the threshold temperature at zero magnetic $\,$ eld.

regim e^{33} . The positions of the peaks, due to a single electron tunneling, allowed them to measure the ground state (GS) energy of a many electron QD. The growth of the magnetic eld yields a crossing between energy levels so that also the GS has a di erent spin polarization. From the measurements K lein et al. could deduce that when the magnetic eld is above a threshold value, the spins ip one by one and the orbitalm om entum increases.

This phenomenon has a quite general explanation in the Hartree-Fock approximation and gives a very interesting phases succession by increasing magnetic eld. In general we can calculate the spin transition eld corresponding to the rst spin ip in the dot, and a second "critical eld" corresponding to the ip of the last spin.

Below we show that the magnetic eld induced spin polarization takes place also in QW s and discuss the theoretical explanation in the general case. The physical mechanism which induces the transitions is very simple: the kinetic energy, proportional to the Ferm i velocity, is strongly reduced by the magnetic eld while the electron electron repulsion is strongly enhanced by the growing eld, especially the repulsion between electrons with opposite spins (this is due to the Hund's rule).

For any model with constant interaction we can nd a general condition for the spin ip and we obtain that the electron spins ip all at the same critical eld. The discrepancy between the observed data and the prediction of this model will be better discussed in a following ar-

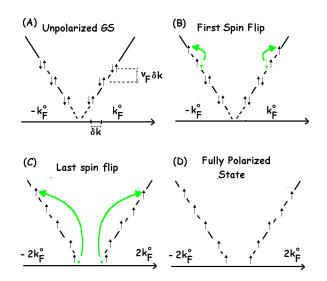


FIG.7:A) Unpolarized state with each state doubly occupied. B) Electrons at the Ferm i surface ip their spins by jumping from the $k_F = N = 4$ doubly occupied to the nearest empty levels ($k_F + k$): First Splin Flip.C) Electrons at the bottom of the subband k = 0 ip their spins by jumping to the rst empty state: Last Spin Flip.D) The fully polarized state.

ticle and is due to the failure of the constant interaction model especially for the dot. The condition in order to allow a spin ip is

$$v_{\rm F}$$
 (!_c) $k = q_{\rm I}^2$ (!_c) $q_{\rm I}^{\rm K}$ (!_c):

We explain in details the case of the electrons near the Ferm i surface and the opposite one of the electrons in the bottom of the subband at k = 0, as we show in Fig.(7). The two electrons at the Ferm isurface can ip their spins only by jumping from the $k_F = N k=4$ doubly occupied to the nearest empty levels $(k_{\rm F} + k)$. This transition is energetically provided if the growth in kinetic energy $2v_F$ k is equal to the reduction in interaction energy with one half of the remaining (N 2) having spin up and the other half with spin down $(2(g_4^2)(!_c))$ ĝ_(!_c))). In the same way we can discuss what happens for two electrons which jump from the bottom of the subband k = 0to the rst empty state, which now has all the levels singly occupied, so that the di erence in kinetic energy is $2v_F \left(\frac{N}{2}\right)$ 1) k, while the gain in interaction energy is given by the spin ip (N 2) $(q_{1}^{c}(!_{c}) q_{1}^{k}(!_{c}))$. Thus, we

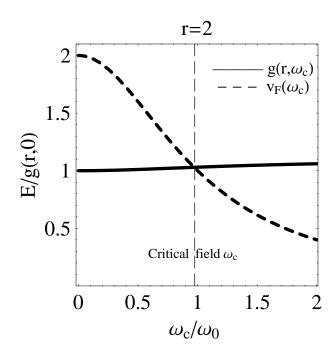


FIG. 8: Graphic calculation of the critical eld for a long range interaction: the spin transition is due to the simultaneous reduction of the Ferm i velocity and increasing of the electron electron repulsion.

can conclude that all the spins ip at the same critical value of the magnetic eld, provided we can consider the interaction as a constant.

This very simple explanation fails if we assume non linear subbands or a long range interaction. In a future article, we will discuss this mechanism in more detail by taking in account also the long range interaction. Here we just want to suggest that the spin polarization takes place and it has some e ects on the interaction param eter: q_i^2 disappears and the Ferm i wavevector doubles yielding a further reduction of g_1 and g_2 . We lim it ourselves to show how the strong magnetic eld has the e ect of reducing the Ferm ivelocity and increasing the electron electron repulsion until a critical phenom enon (spin transition) occurs. In Figs.(1) and (8) we show the critical eld from the crossing between kinetic and repulsion energy. We can conclude that a short range of interaction gives a lower critical eld than a long range interaction. In the gure we just show the dependence of the critical eld on the magnetic eld and on the range of the interaction. In Fig.(9) we report the di erent regimes in the magnetic eld-number of electrons plane, showing the various behaviours of the electron system in the wire when the magnetic eld increases. This diagram is done in analogy with the ones obtained experim entally and theoretically for large Quantum Dots.

In a future article we will also discuss in som e details the chiral Luttinger liquid in a ferrom agnetic state analogous to a spinless system. There, it could be interesting to analyze the spin and charge excitations, in analogy

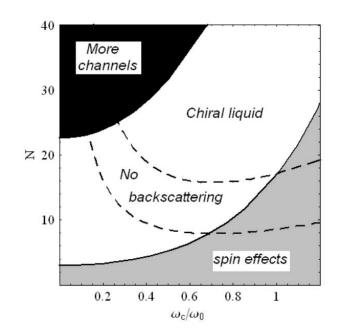


FIG.9: A qualitative phase diagram in the plane magnetic eld-num ber of electrons. We show that increasing the magnetic eld we have the standard case, the backscattering suppression zone, the chiral liquid and the spin polarization. The Number of electrons in the vertical axis in this case is a free choice of the authors, in general it has to be coherent with the L longitudinal dimension of the wire.

with the Quantum Dots and the Quantum Hall Ferromagnets.

V. CONCLUSIONS

In this work we have analyzed some properties of a Q uantum W ire when a strong magnetic eld is present. M ost of the electron electron interaction and the Ferm ivelocity. W hile the Ferm ivelocity always decreases with the magnetic eld, the repulsive interaction between electrons su ers the com petitive actions of the edge state localization and the characteristic length reduction.

W e have described how the grow th of a transversem agnetic eld m odi es the transport properties of a Q uantum W ire under the hypothesis that the latter behaves as a 1 dimensional electron system. In this case, i.e. the one of Luttinger liquids, the tunneling transport properties are due to the large value of the critical exponent

At a low magnetic eld the usual Luttinger liquid behavior is predicted with some e ects due to backscattering. W hen the magnetic eld increases there is a strong reduction of backscattering, while for very high elds also forward scattering between opposite branches vanishes and a chiral Luttinger liquid appears. D uring the growth of the magnetic eld the critical exponent is strongly reduced. A further rise of the eld can cause the spin polarization which takes place as in a large QD, i.e. it does not depend on Zeem an or spin orbit e ects but is due to the combined e ect of the interaction and the magnetic eld.

W e also have discussed how the presence of one in purity can a ect the conductance in the wire. The backward scattering reduction and the rescaling of the electron electron interaction could favor the weak potential limit (strong tunneling) by raising the temperature at which the wire becomes a perfect insulator (G = 0).

In the future we wish to analyze further the possible extension of this form alism to the study of Carbon Nanotubes and discuss with more detail the properties of a Luttinger liquid in a fully polarized state.

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APPENDIX A:COMPARISON BETWEEN COULOMB INTERACTION AND MODEL

In this appendix we discuss the dimension between the Fourier transform softhe C oulom b interaction and of the m odel (eq.(11)).

W e point out that the potential in the form of eq.(11) allows exact integration, in order to obtain the Fourier transform, and it regularizes the divergence appearing in the C oulom b potential. This function could be optimized varying the range parameter r, so that it could be quite similar to the C oulom b potential. The function g($k;!_c$) is plotted for a very short range (r = 0:1) and for various values of magnetic eld in Fig.(10).

The C oulom b potential is not so easy to integrate: we give its transform obtained by a num erical integration

with a sort of regularization near the divergence, and normalized with respect to the value obtained at zero magnetic eld (g(0;0) = 1). Also in this case we show in Fig.(10) the Fourier transform for various values of magnetic eld.

Now we can conclude that the model ts well the Coulom b interaction, if we choose a short range parameter: Fig.(10) shows this good agreem ent.

W e can conclude that a magnetic eld in the lim it of short range gives

$$g(0;!_{c}) \quad g(0;0) \quad \frac{r}{!_{T}}$$

so that we have the strongest interaction between electrons with quite sim ilarm on entum . From Fig.(10 a) and

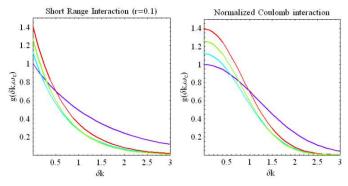


FIG.10: a)On the left, the Fourier transform for various values of magnetic eld of the model of interaction with a short range (0.1). b)On the right, the Coulomb potential case obtained with a numerical calculation and normalized with respect to the value obtained at zero magnetic eld (g(0;0) = 1). A comparison shows a good agreement and an analogous magnetic eld dependence.

Fig.(10 b) we can also argue that the function V (k) decays very rapidly when k increases for high magnetic elds.

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